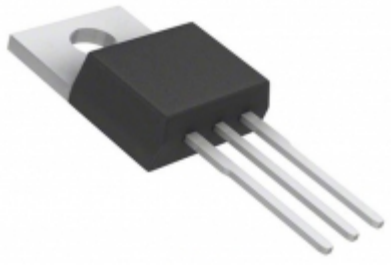


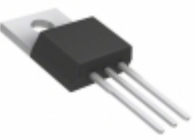
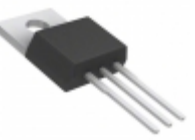



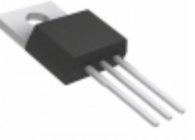
	<h2 style="color: red;">FQP55N06</h2>
	<p>Hersteller-Teilenummer: FQP55N06</p> <p>Hersteller / Marke: Fairchild/ON Semiconductor</p> <p>Teil der Beschreibung: MOSFET N-CH 60V 55A TO-220</p> <p>Datenblätter: 1.FQP55N06.pdf 2.FQP55N06.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 36638 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
 <p style="text-align: center;">Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	FQP55N06
Hersteller	Fairchild/ON Semiconductor
Beschreibung	MOSFET N-CH 60V 55A TO-220
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	36638 pcs Stock
Serie	QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-220-3
Supplier Device-Gehäuse	TO-220-3
Verlustleistung (max)	133W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	60V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	55A (Tc)
Rds On (Max) @ Id, Vgs	20 mOhm @ 27.5A, 10V
VGS (th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	46nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	1690pF @ 25V
Verpackung	Tube



















































FQP55N06 ist neu im Original, Suche FQP55N06 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQP55N06 Fairchild/ON Semiconductor mit Garantie und Vertrauen.
Anfrage FQP55N06: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>FQP58N08 AMI Semiconductor / ON Semiconductor MOSFET N-CH 80V 57.5A TO-220</p>	 <p>FQP55N06 AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 55A TO-220</p>	 <p>FQP58N08 Fairchild/ON Semiconductor MOSFET N-CH 80V 57.5A TO-220</p>	 <p>FQP50N06L AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 52.4A TO-220</p>
 <p>FQP50N06C FAIRCHILD FQP50N06C FAIRCHILD</p>	 <p>FQP50N06L Fairchild/ON Semiconductor MOSFET N-CH 60V 52.4A TO-220</p>	 <p>FQP55N10 Fairchild/ON Semiconductor MOSFET N-CH 100V 55A TO-220</p>	 <p>FQP55N10 AMI Semiconductor / ON Semiconductor MOSFET N-CH 100V 55A TO-220</p>

heiße Teile

Mehr

 FQP46N15	 FQP46N15	 FQP47N06	 FQP47P06	 FQP47P06
 FQP47P06L	 FQP47P06_	 FQP47P06_NW82049	 FQP47P06_NW82049	 FQP47P06_SW82049
 FQP47P06_SW82049	 FQP4N20L	 FQP4N20L	 FQP4N60C	 FQP4N65C
 FQP4N90C	 FQP4N90C	 FQP50N03	 FQP50N03C	 FQP50N06
 FQP50N06	 FQP50N06L	 FQP50N06L	 FQP50N08	 FQP55N06
 FQP55N10	 FQP55N10	 FQP58N08	 FQP58N08	 FQP5N20L
 FQP5N20L	 FQP5N50C	 FQP5N50C	 FQP5N60C	 FQP5N60C
 FQP630TSTU	 FQP630TSTU	 FQP65N06	 FQP65N06	 FQP6N40C
 FQP6N40C	 FQP6N40CF	 FQP6N40CF	 FQP6N50C	 FQP6N50C
 FQP6N60C	 FQP6N60C	 FQP6N80C	 FQP6N80C	 FQP6N90C

Contact us: Info@Y-IC.com

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